

# **PowerSpeech** LOW VOLTAGE ADPCM VOICE SYNTHESIZER

## **GENERAL DESCRIPTION**

The W5230 is a CMOS IC that is used solely for the purpose of demonstrating W523X series Low Voltage *PowerSpeech* products.

The W5230 employs the same JUMP-GO architecture as Winbond's other *PowerSpeech* products. Unlike standard products, however, the W5230 does not include built-in memory, because the chip is designed to serve only as a demonstration chip for the W523X series ICs. Hence the W5230 must be operated with an external memory device (e.g., an OTP memory). The W5230's LOAD and JUMP commands and four programmable registers provide powerful user-programmable functions that make this chip suitable for a wide range of speech IC applications.

#### **FEATURES**

- Wide operating voltage range: 1.2 to 3.6 volts
- Serves as demo chip for W523X series products (no built-in ROM)
- · Programmable speech synthesizer
- 4-bit ADPCM synthesis method and 8-bit D/A converter
- RC oscillator with built-in capacitor; voice output frequency typically at 6 KHz
- · Provides 4 trigger inputs
- · Drives 2 flash LEDs for two batteries
- 3 STOP output signals
- Flexible functions programmable through the following:
  - LD (load), JP (jump) commands
  - Four registers: R0, EN, STOP, and MODE
  - Conditional instructions
  - Speech equation
  - Global repeat (GR) setting
- Programmable power-on initialization (POI), which can be interrupted by trigger inputs
- Interrupt or non-interrupt for rising or falling edge of each trigger pin (this feature determines retriggerable, non-retriggerable, overwrite, and non-overwrite features of each trigger pin)
- LED On/Off control can be set independently in each GO instruction of speech equation
- Independent control of LED 1 and LED 2
- Total of 256 voice group entries available for programming (Including eight hardware and 248 software group entry points)
- 20 to 40 mS debounce time
- Provides the following mask options:

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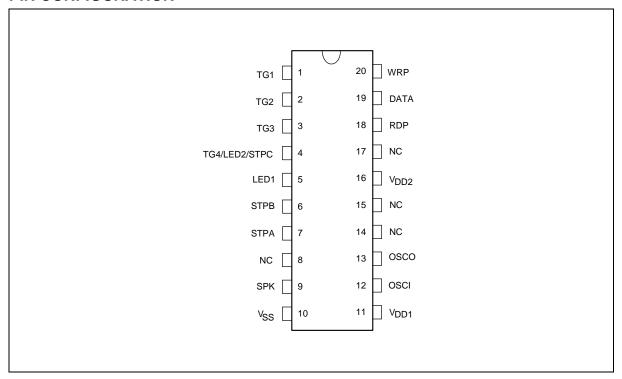
- LED flash frequency: 3 Hz/6 Hz/Off

- LED1 section-controlled: Yes/No

- LED2 section-controlled/STPC-controlled

- AUD output current: 1 mA with one battery, 3 mA with two batteries

# **PIN CONFIGURATION**





# **PIN DESCRIPTION**

NO.	NAME	I/O	FUNCTION
1	TG1	-	Trigger Input 1
2	TG2	_	Trigger Input 2
3	TG3	_	Trigger Input 3
4	TG4/LED2/STPC	I/O	Trigger Input 4 or LED 2 or Stop Signal C
5	LED1	0	LED 1
6	STPB	0	Stop Signal B
7	STPA	0	Stop Signal A
8	NC	-	Not Connected
9	SPK	0	Current Output for Speaker
10	Vss	ı	Negative Power Supply
11	VDD1	1	1.5 V or 3 V Positive Power Supply
12	OSCI	_	Oscillator Input Connect Resistor
13	OSCO	0	Oscillator Output Connect Resistor
14	NC	-	Not Connected
15	NC	ı	Not Connected
16	VDD2	ı	5 V Positive Power Supply
17	NC	ı	Not Connected
18	RDP	0	Read Pulse Clock Output for Serial Interface
19	DATA	I/O	Bidirectional Data Pin for Serial Interface for OTP
20	WRP	0	Write Pulse Clock Output for Serial Interface

# **ABSOLUTE MAXIMUM RATINGS**

PARAMETER	SYMBOL	CONDITIONS	RATING	UNIT
Power Supply VDD-Vs			-0.3 to +5.0	V
Input Voltage	VIN	All Inputs	Vss -0.3 to VDD +0.3	V
Storage Temp.	Tstg		-55 to +150	°C
Operating Temp.	Topr		0 to +70	°C

Note: Exposure to conditions beyond those listed under Absolute Maximum Ratings may adversely affect the life and reliability of the device.



# **ELECTRICAL CHARACTERISTICS**

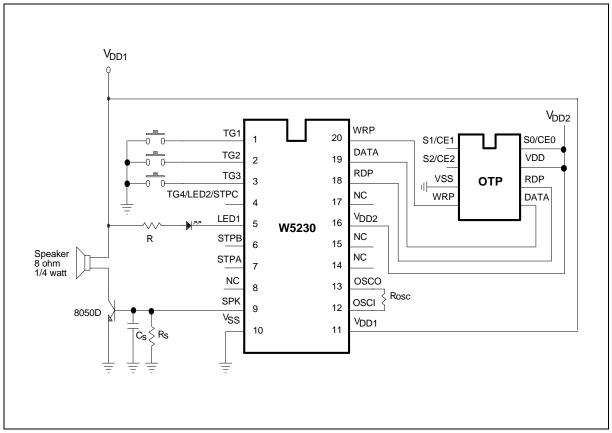
(TA =  $25^{\circ}$  C, Vss = 0 V)

PARAMETER		SYMBOL	CONDITIONS	LIMITS			UNIT
				MIN.	TYP.	MAX.	
Operating Voltage		Vdd	One or Two Batteries	1.2	2.4	3.6	V
Input Voltage		VIL	All Input Pins	Vss -0.3	-	0.3 VDD	V
-		ViH		0.7 Vdd	-	Vdd	
Standby Current		IDD1	VDD = 3 V, No Playing	-	-	0.5	μΑ
			VDD = 1.5 V, No Playing	-	-	0.3	
Operating Current		IOP1	VDD = 3 V, No Load	-	-	400	μΑ
		IOP2	VDD = 1.5 V, No Load	-	-	250	
Input Current for		lin1	VDD = 3 V, VIN = 0 V	-	-	2.5	μΑ
TG1–TG4		lın2	VDD = 1.5 V, VIN = 0 V	-	-	5	
SPK (D/A	Option1	<b>I</b> O1	$VDD = 1.5 \text{ V}, RL = 200 \Omega$	-0.8	-1.0	-1.2	mA
Full Scale)	Option2	l02	$VDD = 3 V$ , $RL = 200 \Omega$	-2.0	-3.0	-4.0	1
	I	lOL1	VDD = 3 V, VIN = 0.4 V	1	-	-	
Output Currer	Output Current		VDD = 1.5 V, VIN = 0.4 V	1	-	-	mA
of SPTC		Іон1	VDD = 3 V, VIN = 2.7 V	-0.5	-	-	-
		Іон2	VDD = 1.5 V, VOUT = 1.2 V	-0.3	-	-	-
	LED1	lo	VDD = 3 V, VOUT = 1 V	6	-	-	
Output		lOL1	VDD = 3 V, VOUT = 0.4 V	1	3	-	
Current	STPA	lol2	VDD = 1.5 V, VOUT = 0.4 V	1	2	-	mA
	STPB	Іон1	VDD = 3 V, VOUT = 2.7 V	-1	-3	-	
		Іон2	VDD = 1.5 V, VOUT = 1.2 V	-0.3	-	-	
Oscillation Freq.		Fosc <sub>1</sub>	VDD = 3 V, Rosc = Typ.	320	384	460	KHz
		Fosc <sub>2</sub>	VDD = 1.5 V, $Rosc = Typ$ .	320	384	460	
Osc. Freq. Deviation by Voltage Drop			F(1.5V) - F(1.2V) F(1.5V)	0	10	20	%
		$\frac{\Delta Fosc}{Fosc}$	F(1.8V) - F(1.5V) F(1.8V)	0	4	7.5	%
			F(3.0V) - F(2.4V) F(3.0V)	0	4	7.5	%
Input Debounce Time		TDEB	Fosc = 384 KHz	20	30	40	mS

Note: Typ. Rosc = 110 K $\Omega$  for two batteries; 100 K $\Omega$  for one battery.



# TYPICAL APPLICATION CIRCUIT

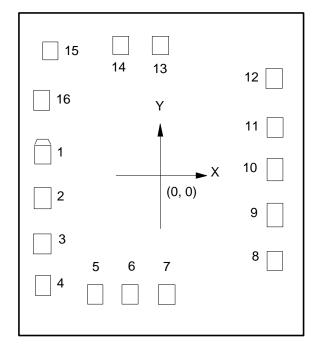


### Notes:

- 1. In principle, the playing speed determined by Rosc should correspond to the sampling rate during the coding phase. The playing speed may be adjusted by varying Rosc, however.
- 2. Rs is an optional current-dividing resistor. If Rs is added, the resistance should be between 470 and 750.
- 3. R is used to limit the current the LED.
- 4. Cs is optional.
- 5. The DC current gain  $\beta$  of transistor 8050 ranges from 120 to 200.
- 6. All unused trigger pins can be left open because of their internal pull-high resistance.
- 7. No warranty for production.



# **BONDING PAD DIAGRAM**



NO.	PAD NAME
1	TG1
2	TG2
3	TG3
4	TG4/LED2/STPC
5	LED1
6	STPB
7	STPA
8	SPK
9	Vss
10	VDD1
11	OSCI
12	OSCO
13	VDD2
14	RDP
15	DATA
16	WRP

Note: Substrate is tied to Vss.



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Note: All data and specifications are subject to change without notice.